

NANO EXPRESS

Open Access

Singly ionized double-donor complex in vertically coupled quantum dots

Ramón Manjarres-García¹, Gene Elizabeth Escorcía-Salas¹, Iliia D Mikhailov² and José Sierra-Ortega^{1*}

Abstract

The electronic states of a singly ionized on-axis double-donor complex (D_2^+) confined in two identical vertically coupled, axially symmetrical quantum dots in a threading magnetic field are calculated. The solutions of the Schrödinger equation are obtained by a variational separation of variables in the adiabatic limit. Numerical results are shown for bonding and antibonding lowest-lying artificial molecule states corresponding to different quantum dot morphologies, dimensions, separation between them, thicknesses of the wetting layers, and magnetic field strength.

Keywords: Quantum dots, Adiabatic approximation, Artificial molecule

PACS: 78.67.-n, 78.67.Hc, 3.21.-b

Background

Quantum dots (QDs) have opened the possibility to fabricate both artificial atoms and molecules with novel and fascinating optoelectronic properties which are not accessible in bulk semiconductor materials. An attractive route for nano-structuring semiconductor materials offers self-assembled quantum dots which are formed by the Stranski-Krastanow growth mode by depositing the material on a substrate with different lattice parameters [1-5]. The electrical and optical properties of these structures may be changed in a controlled form by doping the shallow impurities whose energy levels are defined by the interplay between the reductions of the physical dimension, the Coulomb attraction, and the inter-particle correlation.

Recently, it has been proposed to use the singly ionized double-donor system (D_2^+) confined in a single semiconductor QD [6] or ring [7] as an adequate functional part in a wide range of device applications, including spintronics, optoelectronics, photovoltaics, and quantum information technologies. This two-level system encodes logical information either on the spin or on the charge degrees of freedom of the single electron and allows us to manipulate conveniently its molecular

properties, such as the energy splitting between the bonding and antibonding lowest-lying molecular-like states or the spatial distribution of carriers in the system [8-12]. One can expect that the singly ionized double-donor system (D_2^+) confined in vertically coupled QDs should have similar properties. In this paper, we analyze the electronic states of an artificial hydrogen molecular ion (D_2^+) compound by two positive ions that interchange their electron, which is constrained to exchange between two identical vertically coupled, axially symmetrical QDs in the presence of a threading magnetic field.

Methods

Below, we analyze the model of two separated on-axis singly ionized donors, confined in two coaxial, vertically stacked QDs, whose identical morphologies present axially symmetrical layers whose shape is given by the dependence of the layer thickness h on the distance ρ from the axis as follows: $h(\rho) = d_b + d_0 f_n(\rho) \vartheta(R_0 - \rho)$. Here, R_0 is the base radius, d_b is the wetting layer thickness, d_0 is the maximum height of the QD over this layer, $\vartheta(x)$ is the Heaviside step function, equal to 0 for $x < 0$ and to 1 for $x > 0$, and $f_n(\rho) = [1 - (\rho/R_0)^n]^{1/n}$. The morphology is controlled in this model by means of the integer shape-generating parameter n which is equal to 1, 2, or tends to infinity for conical pyramid-like, lens-like, and disk-like geometrical shapes, respectively. As an example, the 3D image of an artificial singly ionized

* Correspondence: jsierraortega@gmail.com

¹Group of Investigation in Condensed Matter Theory, Universidad del Magdalena, Santa Marta, Colombia

Full list of author information is available at the end of the article

molecule confined in lens-like QDs is presented in Figure 1.

Besides, we assume that the external homogeneous magnetic field $\mathbf{B} = B\hat{z}$ is applied along the quantum dot's axis. The dimensionless Hamiltonian of the single electron in this D_2^+ complex in the effective-mass approximation can be written as

$$H = -\Delta + V_c(\rho, z) - \frac{2}{|\mathbf{r} - \mathbf{R}_1|} - \frac{2}{|\mathbf{r} - \mathbf{R}_2|}; \mathbf{R}_i = (0, z_i, 0) \quad (1)$$

where $V_c(\rho, z)$ is the confinement potential, equal to 0 and V_0 inside and outside the QD, respectively. The last two terms in Equation 1 correspond to the attraction between electron and ions. The effective Bohr radius $a_0^* = \hbar^2 \epsilon / m^* e^2$, the effective Rydberg $R_y^* = e^2 / 2\epsilon a_0^*$, and $\gamma = e\hbar B / 2m^* c R_y^*$ have been taken above as units of length, energy, and the conventional dimensionless magnetic field strength, respectively.

As both donors are located at the axis, the potential is axially symmetrical, the angular momentum L_z commutes with the Hamiltonian, and the corresponding eigenvalues give us one good quantum number m . At this representation, the Hamiltonian (Equation 1) cylindrically coordinates only on two coordinates:

$$H_m(\rho, z) = -\frac{1}{\rho} \frac{\partial}{\partial \rho} \rho \frac{\partial}{\partial \rho} - \frac{\partial^2}{\partial z^2} + \gamma m + \frac{\gamma^2 \rho^2}{4} + V_\rho(\rho, z);$$

$$V_\rho(\rho, z) = V_c(\rho, z) - \frac{2}{\sqrt{\rho^2 + (z - Z_1)^2}} - \frac{2}{\sqrt{\rho^2 + (z - Z_2)^2}}. \quad (2)$$

Taking into account that the thickness of QDs is typically much smaller than their lateral dimension and

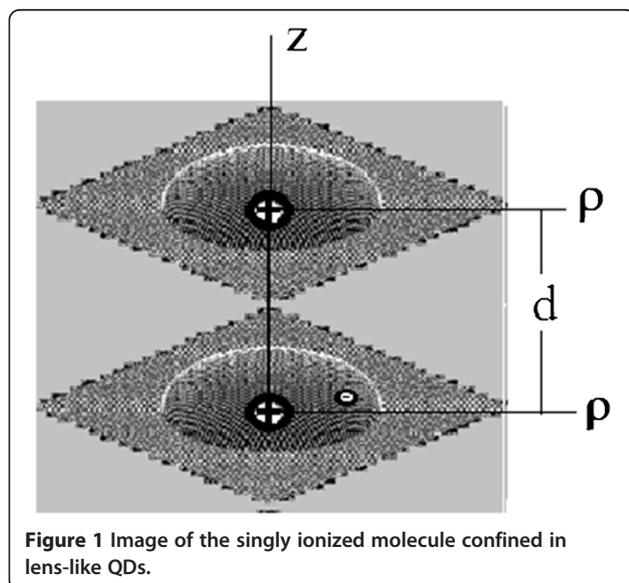


Figure 1 Image of the singly ionized molecule confined in lens-like QDs.

therefore the electron motion in the first direction is much faster than in-plane motion, one can use the advantage of the adiabatic approximation [13] in which the wave function is presented as a product of two functions:

$$\Psi_m(\rho, z) = f(\rho, z) \Phi_m(\rho); m = 0, \pm 1, \pm 2, \dots, \quad (3)$$

where the first function $f(\rho, z)$ describes the fast motion in z direction and satisfies the wave equation

$$-\frac{\partial^2 f(\rho, z)}{\partial z^2} + V(\rho, z) f(\rho, z) = E_f(\rho) f(\rho, z) \quad (4)$$

with 'frozen out' radial coordinate ρ , while the radial part of the wave function is found in the second step from the equation

$$\frac{1}{\rho} \frac{\partial}{\partial \rho} \rho \frac{\partial \Phi_m(\rho)}{\partial \rho} + \left[\gamma m + \frac{m^2}{\rho^2} + \frac{\gamma^2 \rho^2}{4} + E_f(\rho) \right] \Phi_m(\rho) = E_m \Phi_m(\rho). \quad (5)$$

In our numerical procedure, we solve Equation 4 repeatedly for each value ρ by using the trigonometric sweep method [13] in order to restore the unknown function $E_f(\rho)$. Once this function is found, then the energies E_m of the molecular complex can be established by solving Equation 5.

As the potential $V(\rho, z)$ for each fixed value of ρ presents an even function $V(\rho, -z) = V(\rho, z)$ with respect to the variable z corresponding to a symmetrical (no-rectangle) quantum well, then all solutions of Equation 4 can be arranged in two sets: odd solutions $f^-(\rho, -z) = -f^-(\rho, z)$ and even solutions $f^+(\rho, -z) = f^+(\rho, z)$, called anti-bonding and bonding states, respectively. These sets of functions can be found as the solutions of the boundary value problems corresponding to the differential Equation 4 within the range $0 < z < \infty$ with the frontier conditions $\frac{df^+(\rho, 0)}{dz} = 0; f^-(\rho, 0) = 0$.

Results and discussion

We have performed numerical calculations of two-electron renormalized energies E_m as a function of the magnetic flux and for QDs with different morphologies, dimensions, and separation between layers in order to analyze the Aharonov-Bohm and the quantum size effects. We consider for our simulations the $\text{In}_{0.55}\text{Al}_{0.45}\text{As}/\text{Al}_{0.35}\text{Ga}_{0.65}\text{As}$ structures with the following values of physical parameters: dielectric constant = 12.71, the effective mass in the dot region and the region outside the dot for the electron $m^* = 0.076m_0$, the conduction and the valence band offset in junctions is $V_0 = 358\text{meV}$, the effective Bohr radius $a_0^* \approx 10\text{nm}$, and the effective Rydberg $R_y^* \approx 5\text{meV}$.

First, we calculate the energies of the molecular complex as functions of the magnetic field in disk-like, lens-like, and cone-like vertically coupled QDs and in a single one-electron QR with smooth non-homogeneity of the surface. Results for vertically coupled QDs with the heights $d_0 = 4\text{nm}$, the wetting layer thicknesses $d_b = 1\text{nm}$, radii $R_0 = 20\text{nm}$, and the separation between them $d = 6\text{nm}$ are shown in Figure 2.

It is seen that in all cases, the energy levels are very sensitive to the magnetic field and their dependencies on the magnetic field strength exhibit multiple crossovers and reordering. Comparing these dependencies for the disk, the lens, and the cone in Figure 2, one can also observe a successive increase of the number of

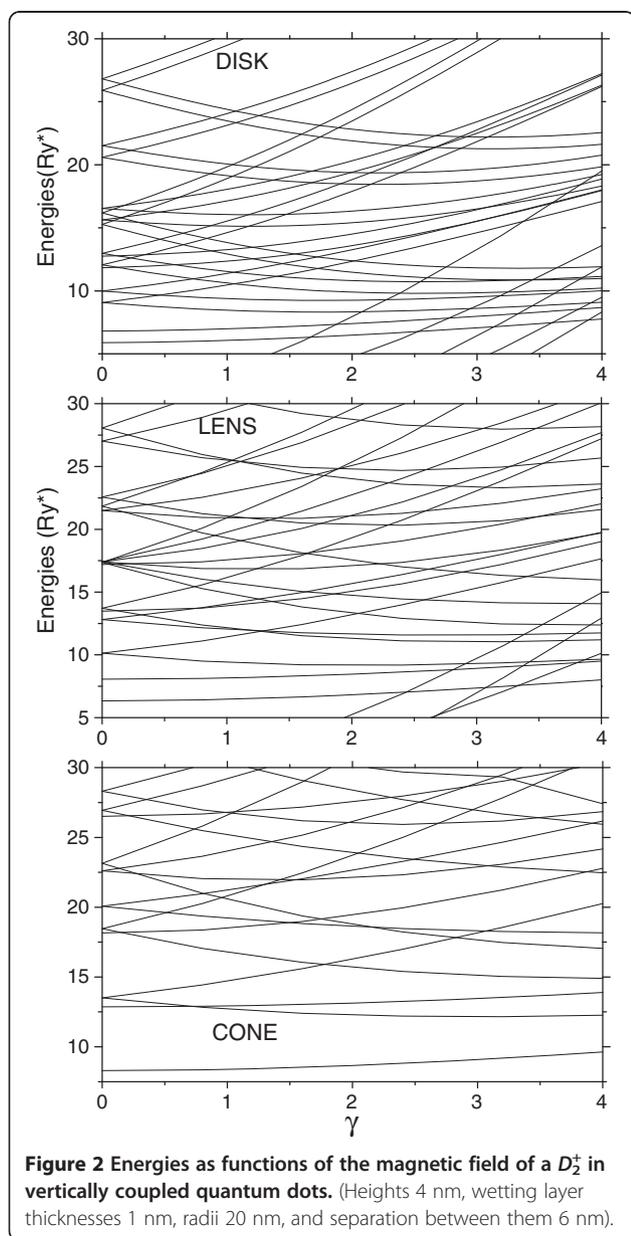


Figure 2 Energies as functions of the magnetic field of a D_2^+ in vertically coupled quantum dots. (Heights 4 nm, wetting layer thicknesses 1 nm, radii 20 nm, and separation between them 6 nm).

crossovers and the lowering of the region energies where such crossovers occur. It is related to the variation of the electron probability distribution inside and around their InAs layers, which is similar to charge distribution in a metallic surface when its geometry varies from the flat to the spiked-type one. Such variation of the probability distribution is a consequence of the stronger confinement in structures with spiked-type QD geometry where the electron-ion separation is defined by interplays between the electrostatic interaction between them and the strong structural confinement, making it more stable with respect to the external magnetic field and the ring-like electron probability density distribution. Therefore, the energy dependencies for cone-like QDs have a shape similar to those that exhibit structures with ring-like geometry known as the Aharonov-Bohm effect.

The Aharonov-Bohm effect observed usually in ring-like heterostructures is a manifestation of the competition between the paramagnetic and diamagnetic terms in the Hamiltonian, resulting in the oscillation of the ground state energy. Such oscillations are impossible in the disk-like structures because of a significant decrease of the diamagnetic term contribution as the magnetic field increases and the electron probability distribution becomes more contracted. In QDs with a spike-like morphology, the electron probability density is already strongly confined, the external magnetic field can no longer decrease more the diamagnetic term contribution, and the energy dependencies on the increasing magnetic field become similar to those of ring-like structures.

In Figure 3, we present results of the calculation of the density of electronic states in the zero-magnetic field for QDs with three different morphologies on the left side case $\gamma = 0$ and on the right side for $\gamma = 0.8$. It is seen that the density of electronic states in the case of the zero-magnetic field for the disk-like structure has a larger value in the region of the low-lying energy levels and it decreases successively while the morphology becomes more and more spike-like. It is due to the fact that the electron confinement in the disk is weaker than that in the lens and that in the lens is weaker than that in the cone.

Also, it is seen that the lowest peak corresponding to the ground bonding state in the cone-like structure is more significantly separated from other excited states than in two other structures. It is due to the stronger confinement of the electron in the cone-like structure where the electron is mainly located nearer to the donor than in disk-like and lens-like structures.

Comparing the densities of states presented on the left and right sides of Figure 3, one can see remarkable modifications that suffer the corresponding curves. Particularly, in the disk-like structure, the presence of the

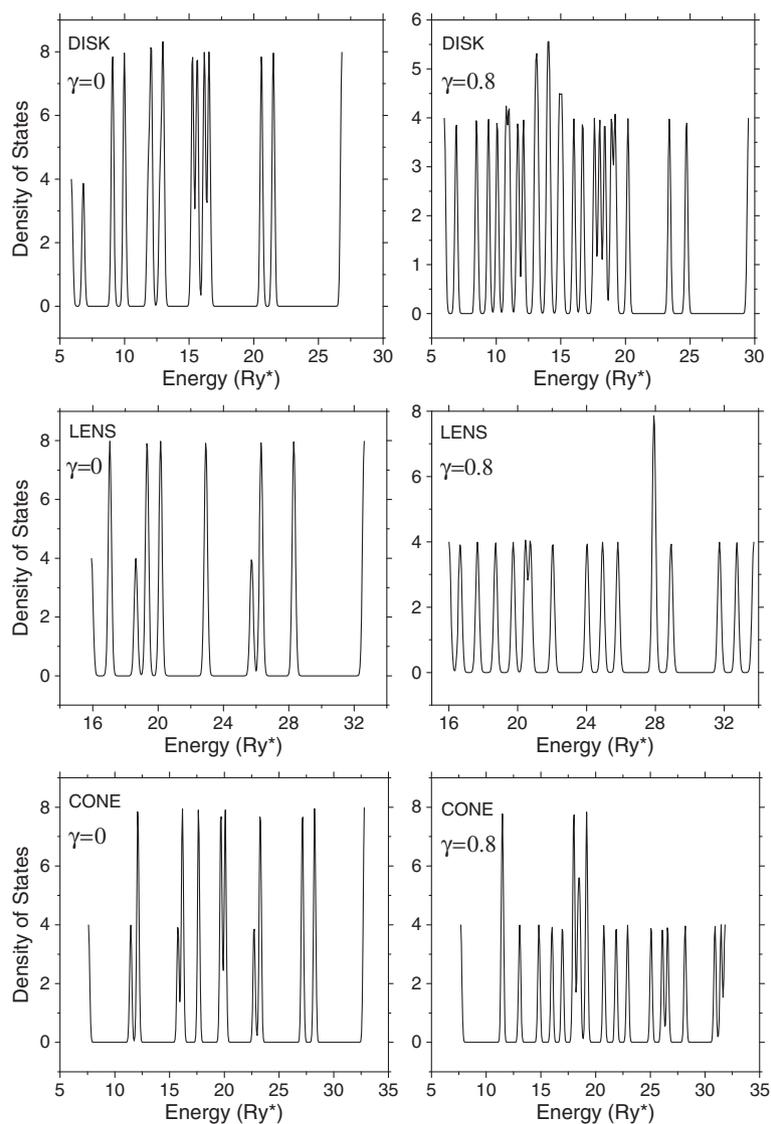


Figure 3 Density of the electronic states for a D_2^+ in vertically coupled quantum dots. (Heights 3 nm, wetting layer thicknesses 2 nm, radii 20 nm, and separation between them 6 nm for two different values of the magnetic field ($\gamma = 0$) and ($\gamma = 0.8$)).

magnetic field provides a displacement of the peaks at the region of the low-lying energies. In the lens-like and cone-like structures, the modification is inverted; the peaks are reorganized in such a way that their distribution becomes almost homogeneous. Redistribution of the peaks' positions in the lens is defined mainly by the additional confinement that provides the external magnetic field, while analogous redistribution in other two spike-like structures is mainly due to the Aharonov-Bohm effect.

Conclusions

In short, we propose a simple numerical procedure for calculating the energies and wave functions of a singly

ionized molecular complex formed by two separated on-axis donors located at vertically coupled QDs in the presence of the external magnetic field. Our calculation includes some important characteristics of the heterostructure such as the presence of the wetting layer and the possibility of the variation of the QD morphology. The curves of the energy dependencies on the external magnetic field for the disk-like, lens-like, and cone-like structures are presented. We find that the effect of the in-plane confinement on the electron-ion separation is stronger in spike-shaped QDs and therefore the energy dependencies in such structures exhibit a behavior similar to that in ring-like structures. The analysis of the curves of the density of electronic states also confirms this result.

Competing interests

The authors declare that they have no competing interests.

Authors' contributions

All authors contributed equally to this work. JSO created the analytic model with contributions from IM. RMG and GES performed the numerical calculations and wrote the manuscript. All authors discussed the results and implications and commented on the manuscript at all stages. All authors read and approved the final manuscript.

Authors' information

JSO obtained his Ph.D. in 2004 at the Universidad Industrial de Santander, where IM was his advisor. His research interests include the theory of semiconductor nanostructures. JSO is the head of the research group 'Condensed Matter Theory' at the University of Magdalena. GES and RMG are master's degree and Ph.D. students, respectively, and teachers at the University of Magdalena.

Acknowledgements

This work was financed by the Universidad del Magdalena through the Vicerrectoría de Investigaciones (Código 01).

Author details

¹Group of Investigation in Condensed Matter Theory, Universidad del Magdalena, Santa Marta, Colombia. ²Universidad Industrial de Santander, A. A. 678, Bucaramanga, Colombia.

Received: 10 July 2012 Accepted: 3 August 2012

Published: 31 August 2012

References

1. Jacak L, Hawrylak P, Wójs A: *Quantum Dots*. Berlin: Springer; 1997.
2. Leonard D, Pond K, Petroff PM: **Critical layer thickness for self-assembled InAs islands on GaAs**. *Phys Rev B* 1994, **50**:11687–11692.
3. Lorke A, Luyken RJ, Govorov AO, Kotthaus JP: **Spectroscopy of nanoscopic semiconductor rings**. *Phys Rev Lett* 2000, **84**:2223–2226.
4. Granados D, García JM: **In(Ga)As self-assembled quantum ring formation by molecular beam epitaxy**. *Appl Phys Lett* 2003, **82**:2401.
5. Raz T, Ritter D, Bahir G: **Formation of InAs self-assembled quantum rings on InP**. *Appl Phys Lett* 2003, **82**:1706.
6. Movilla JL, Ballester A, Planelles J: **Coupled donors in quantum dots: quantum size and dielectric mismatch effects**. *Phys Rev B* 2009, **79**:195319.
7. Gutiérrez W, García LF, Mikhailov ID: **Coupled donors in quantum ring in a threading magnetic field**. *Physica E* 2010, **43**:559.
8. Calderón MJ, Koiller B: **External field control of donor electron exchange at the Si/SiO₂ interface**. *Phys Rev B* 2007, **75**:125311.
9. Tsukanov AV: **Single-qubit operations in the double-donor structure driven by optical and voltage pulses**. *Phys Rev B* 2007, **76**:035328.
10. Openov LA: **Resonant pulse operations on the buried donor charge qubits in semiconductors**. *Phys Rev B* 2004, **70**:233313.
11. Koiller B, Hu X: **Electric-field driven donor-based charge qubits in semiconductors**. *Phys Rev B* 2006, **73**:045319.
12. Barrett SD, Milburn GJ: **Measuring the decoherence rate in a semiconductor charge qubit**. *Phys Rev B* 2003, **68**:155307.
13. Mikhailov ID, Marín JH, García LF: **Off-axis donors in quasi-two-dimensional quantum dots with cylindrical symmetry**. *Phys Stat Sol (b)* 2005, **242**:1636.

doi:10.1186/1556-276X-7-489

Cite this article as: Manjarres-García et al.: Singly ionized double-donor complex in vertically coupled quantum dots. *Nanoscale Research Letters* 2012 **7**:489.

Submit your manuscript to a SpringerOpen[®] journal and benefit from:

- Convenient online submission
- Rigorous peer review
- Immediate publication on acceptance
- Open access: articles freely available online
- High visibility within the field
- Retaining the copyright to your article

Submit your next manuscript at ► springeropen.com